## NSN 5961-01-513-7812

Transistor - Page 1 of 1



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|--|
| Overall Height:  |
| Between 0.250 inches and 0.450 inches  |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation:                                      |
| To-3   |
| Mounting Method:   |
| Unthreaded hole  |
| Semiconductor Material:  |
| Silicon  |
| Voltage Rating In Volts Per Characteristic:  |
| 80.0 collector to base voltage, dc and 60.0 collector to emitter voltage, dc and 7.0 emitter to base voltage, dc |
| Current Rating Per Characteristic:   |
| 10.00 amperes source cutoff current  |
| Power Rating Per Characteristic:   |
| 150.0 watts small-signal input power, common-collector absolute  |
| Terminal Type And Quantity:  |
| 1 case and 2 pin   |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| No   |
| Fiig:  |
| A110a0   |